### **Translating Bus Exchange Switch**

### **7WBD383**

The 7WBD383 is an advanced high-speed low-power translating bus exchange switch in ultra-small footprints.

#### **Features**

- High Speed:  $t_{PD} = 0.25 \text{ ns (Max)} @ V_{CC} = 4.5 \text{ V}$
- 3 Ω Switch Connection Between 2 Ports
- Power Down Protection Provided on Inputs
- Zero Bounce
- TTL-Compatible Control Inputs
- Ultra-Small Pb-Free Packages
- These are Pb-Free Devices



#### ON Semiconductor®

#### www.onsemi.com

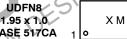
#### **MARKING DIAGRAMS**



**UDFN8 MU SUFFIX** CASE 517AJ









Micro8 DM SUFFIX CASE 846A





**UQFN8 MU SUFFIX** CASE 523AN





US8 **US SUFFIX CASE 493** 



Commercial

AL, X, D383, AJ, AG

= Specific Device Code = Date Code

= Assembly Location

= Lot Code

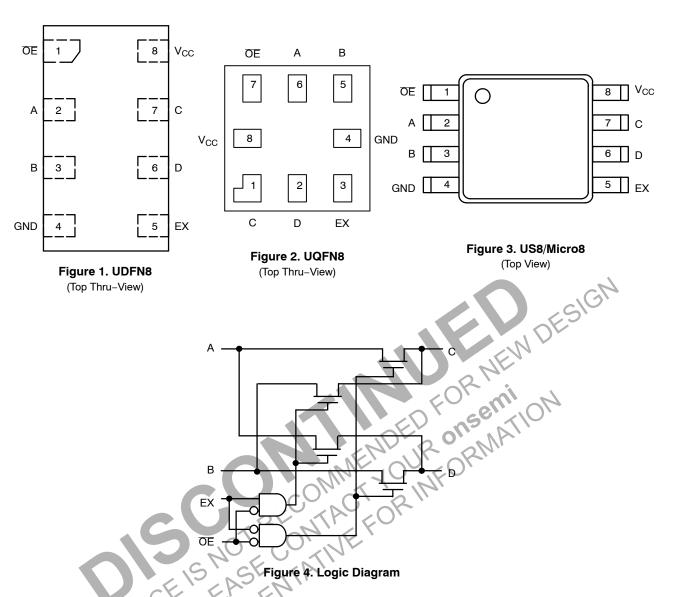
= Year Code = Week Code = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



## FUNCTION TABLE

Input OE	Input EX	Function
L	L	A = C; B = D
L	Н	A = D; B = C
Н	X	Disconnect

#### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IN</sub>	Control Pin Input Voltage	-0.5 to +7.0	V
V <sub>I/O</sub>	Switch Input / Output Voltage	-0.5 to +7.0	V
I <sub>IK</sub>	Control Pin DC Input Diode Current V <sub>IN</sub> < GND	-50	mA
l <sub>OK</sub>	Switch I/O Port DC Diode Current V <sub>I/O</sub> < GND	-50	mA
Io	ON-State Switch Current	± 128	mA
	Continuous Current Through V <sub>CC</sub> or GND	± 150	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	± 150	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	± 150	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	<b>√</b> °C
TJ	Junction Temperature Under Bias	150	O °C
$\theta_{\sf JA}$	Thermal Resistance US8 (Note 1) UDFN8 UQFN8 Micro8	251 111 208 392	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C  US8  UDFN8  UQFN8  Micro8	498 1127 601 319	mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage  Human Body Mode (Note 2)  Machine Model (Note 3)  Charged Device Model (Note 4)	> 2000 > 200 N/A	V
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below GND at 125 °C (Note 5)	±200	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

- Tested to EIA / JESD22-A114-A.
   Tested to EIA / JESD22-A115-A.
- Tested to JESD22-C101-A.
- 5. Tested to EIA / JESD78.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		4.0	5.5	V
V <sub>IN</sub>	Control Pin Input Voltage		0	5.5	V
V <sub>I/O</sub>	Switch Input / Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate Control I Switch		0 0	5 DC	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC ELECTRICAL CHARACTERISTICS

			Voc	V <sub>CC</sub>		С	T <sub>A</sub> = -55°C to +125°C		
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Unit
V <sub>IK</sub>	Clamp Diode Voltage	I <sub>I/O</sub> = -18 mA	4.5			-1.2		-1.2	V
V <sub>IH</sub>	High-Level Input Voltage (Control)		4.0 to 5.5	2.0			2.0		V
V <sub>IL</sub>	Low-Level Input Voltage (Control)		4.0 to 5.5			0.8		0.8	V
V <sub>OH</sub>	Output Voltage High	See Figure 5							
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±0.1		±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>I/O</sub> = 0 to 5.5 V	0			±0.1		±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$I_{O} = 0,$ $V_{IN} = V_{CC} \text{ or } 0 \text{ V}$ $\overline{OE} = GND$ $\overline{OE} = V_{CC}$	5.5			±1.0 ±0.1		±1.0 ±1.0	mA μA
Δl <sub>CC</sub>	Increase in Supply Current (Control Pin)	One input at 3.4 V; Other inputs at V <sub>CC</sub> or GND	5.5				NDE	2.5	mA
R <sub>ON</sub>	Switch ON Resistance	$V_{I/O} = 0,$ $I_{I/O} = 64 \text{ mA}$ $I_{I/O} = 30 \text{ mA}$	4.5		3 3	7		7 7	Ω
		V <sub>I/O</sub> = 2.4, I <sub>I/O</sub> = 15 mA		CO	15	50	(10/4	50	
		$V_{I/O} = 2.4,$ $I_{I/O} = 15 \text{ mA}$	4.0		50	270		70	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# AC ELECTRICAL CHARACTERISTICS

		0, CO/1/	V <sub>CC</sub>	1	Γ <sub>A</sub> = 25 °	С		\ = > +125°C	
Symbol	Parameter S	Test Condition	(v)	Min	Тур	Max	Min	Max	Unit
t <sub>PD</sub>	Propagation Delay, Bus to Bus	See Figure 6	4.0 to 5.5			0.25		0.25	ns
t <sub>PD-EX</sub>	Propagation Delay, EX to Bus	See Figure 6 and Figure 7	4.0 to 5.5			4.5		4.5	ns
t <sub>EN</sub>	Output Enable Time	See Figure 6	4.5 to 5.5	0.8	2.5	4.2	0.8	4.2	ns
			4.0	0.8	3.0	4.6	0.8	4.6	
t <sub>DIS</sub>	Output Disable Time		4.5 to 5.5	0.8	3.0	4.8	0.8	4.8	ns
			4.0	0.8	2.9	4.4	0.8	4.4	1
C <sub>IN</sub>	Control Input Capacitance	V <sub>IN</sub> = 5 or 0 V	5.0		2.5				pF
C <sub>IO(ON)</sub>	Switch On Capacitance	Switch ON	5.0		10				pF
C <sub>IO(OFF)</sub>	Switch Off Capacitance	Switch OFF	5.0		5				pF

#### **TYPICAL DC CHARACTERISTICS**

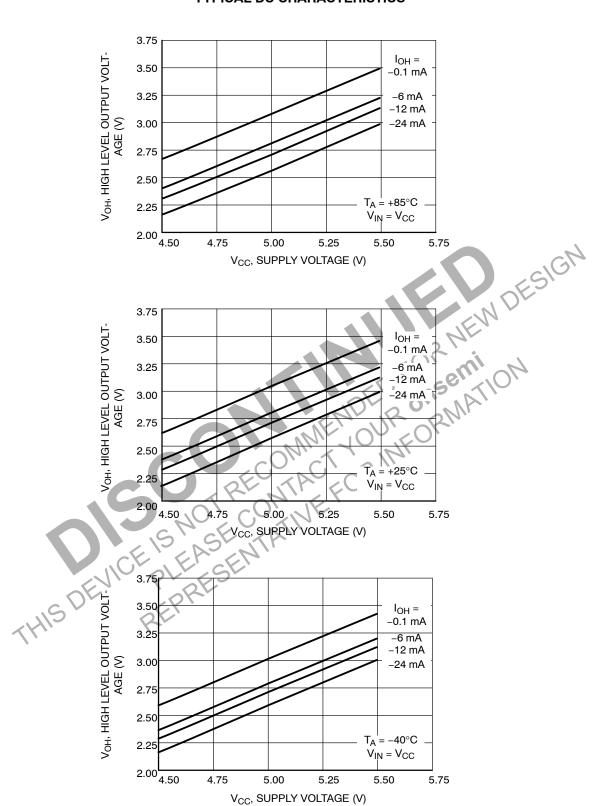
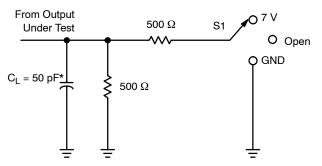


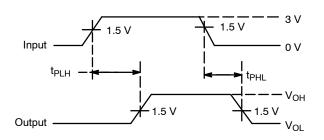
Figure 5. Output Voltage High vs Supply Voltage

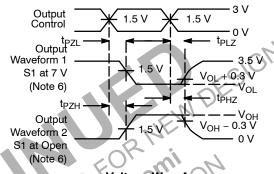
#### **AC LOADING AND WAVEFORMS**



Test	S1
t <sub>PD</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	7 V
t <sub>PHZ</sub> /t <sub>PZH</sub>	Open

<sup>\*</sup>C<sub>L</sub> includes probes and jig capacitance.



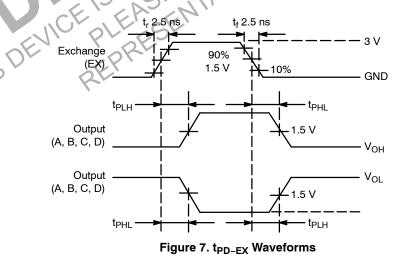


#### **Voltage Waveforms Propagation Delay Times**

Voltage Waveforms **Enable and Disable Times** 

- 6. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control
   7. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≤ 2.5 ns, t<sub>f</sub> ≤ 2.5 ns.
- 8. The outputs are measured one at a time, with one transition per measurement.
- 9.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{DIS}$ .
- $10.t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN}$ .
- 11.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{PD}$

t<sub>DIS</sub> Loading and Waveforms Figure 6. t<sub>PD</sub>, t<sub>EN</sub>,



#### **ORDERING INFORMATION**

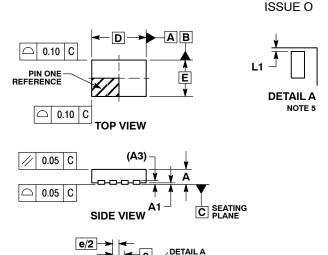
Device	Package	Shipping <sup>†</sup>
7WBD383USG	US8 (Pb-Free)	3000 / Tape & Reel
7WBD383MUTAG	UDFN8 (Pb-Free)	3000 / Tape & Reel
7WBD383AMUTCG	UQFN8 (Pb-Free)	3000 / Tape & Reel
7WBD383DMR2G	Micro8 (Pb-Free)	4000 / Tape & Reel
7WBD383DMUTCG	UDFN8, 1.95 x 1.0, 0.5 mm Pitch (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



#### PACKAGE DIMENSIONS

#### **UDFN8 1.8 x 1.2, 0.4P** CASE 517AJ



-8x L

8x b

Ф

**BOTTOM VIEW** 

0.10 M

CAB

0.05 M C NOTE 3

(b2)

#### NOTES:

- NOTES:

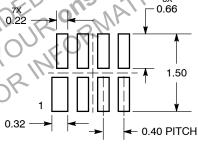
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. DIMENSION 6 APPLIES TO PLATED TERMINAL AND 1S MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
- MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY NOT EXCEED 0.03 ONTO BOTTOM SURFACE OF TERMINALS.
- 5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

	MILLIM	ETERS
DIN	MIN	MAX
Α	0.45	0.55
A1	0.00	0.05
АЗ	0.127	REF
b	0.15	0.25
b2	0.30	REF
D.	1.80	BSC
E	1.20	BSC
е	0.40	BSC \
L	0.45	0.55
L1	0.00	0.03
Ľ2	0.40	RÉF

# MOUNTING FOOTPRINT\* SOLDERMASK DEFINED

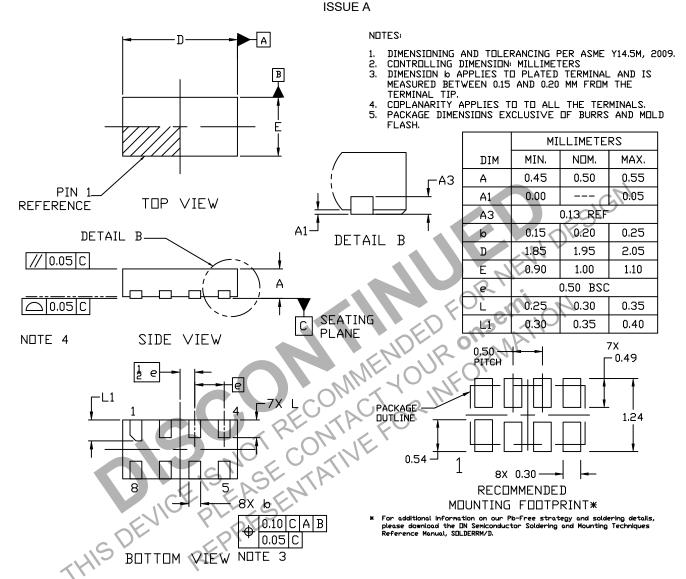


**DIMENSIONS: MILLIMETERS** 

THIS DEVICE PLEASENTATIVE PLEASENTATIVE PLEASENTATIVE PLEASENTATIVE \*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

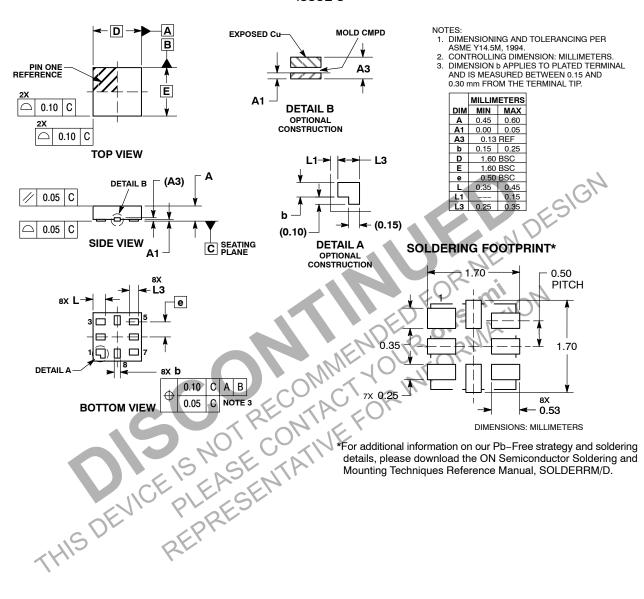
#### **PACKAGE DIMENSIONS**

### UDFN8 1.95x1.0, 0.5P CASE 517CA



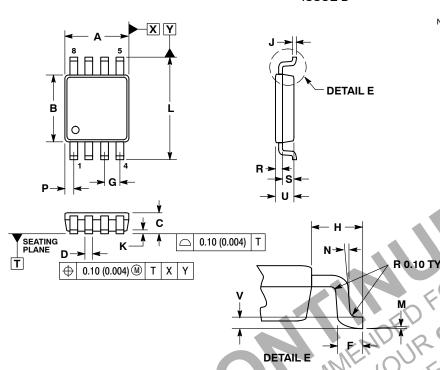
#### PACKAGE DIMENSIONS

#### UQFN8, 1.6x1.6, 0.5P CASE 523AN ISSUE O



#### PACKAGE DIMENSIONS

#### US8 **CASE 493** ISSUE D



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

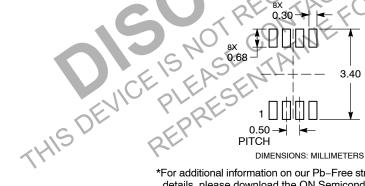
  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR. MOLD FLASH. PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.14MM (0.0055") PER SIDE.

  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH AND PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT EXCEED 0.14MM (0.0055") PER SIDE.
- AND PROTROSON SHALL NOT EXCEED 0.14WW (0.0055") PER SIDE. LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203MM (0.003-0.008"). ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508MM (0.0002").

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.90	2.10	0.075	0.083
В	2.20	2.40	0.087	0.094
Ç	0.60	0.90	0.024	0.035
D	0.17	0.25	0.007	0.010
F	0.20	0.35	0.008	0.014
G	0.50	BSC	0.020	BSC
H	0.40	0.40 REF		REF
J	0.10	0.18	0.004	0.007
_K \	0.00	0.10	0.000	0.004
۲	3.00	3.20	0.118	0.128
M	0	6 °	0°	6°
N	0 °	10 %	0 °	10 °
P (	0.23	0.34	0.010	0.013
R	0.23	0.33	0.009	0.013
S	0.37	0.47	0.015	0.019
U	0.60	0.80	0.024	0.031
۸	0.12 BSC		0.005	BSC

# RECOMMENDED SOLDERING FOOTPRINT\*

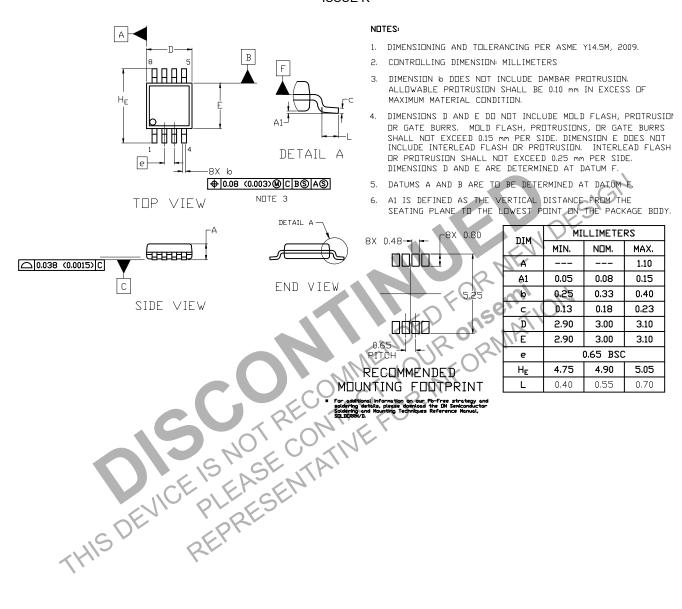


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

#### Micro8 CASE 846A ISSUE K



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